

To all our customers

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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

Cautions

Keep safety first in your circuit designs!

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Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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2SC2396, 2SC2543, 2SC2544

Silicon NPN Epitaxial

RENESAS

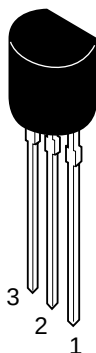
ADE-208-1062A (Z)
2nd. Edition
Mar. 2001

Application

- Low frequency amplifier

Outline

TO-92 (1)



1. Emitter
2. Collector
3. Base

2SC2396, 2SC2543, 2SC2544

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	2SC2396	2SC2543	2SC2544	Unit
Collector to base voltage	V _{CBO}	60	90	120	V
Collector to emitter voltage	V _{CEO}	60	90	120	V
Emitter to base voltage	V _{EBO}	5	5	5	V
Collector current	I _C	100	100	100	mA
Emitter current	I _E	−100	−100	−100	mA
Collector power dissipation	P _C	400	400	400	mW
Junction temperature	T _j	150	150	150	°C
Storage temperature	T _{stg}	−55 to +150	−55 to +150	−55 to +150	°C

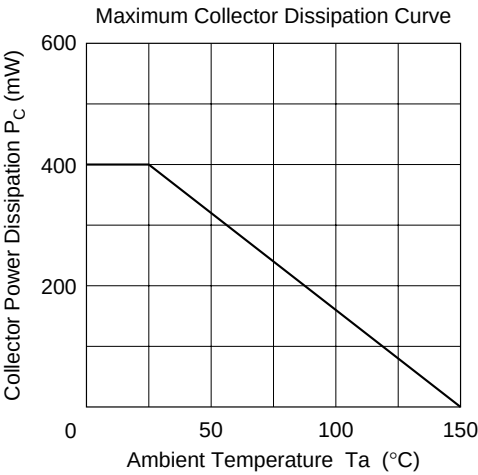
Electrical Characteristics (Ta = 25°C)

Item	Symbol	2SC2396			2SC2543			2SC2544			Unit	Test conditions
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
Collector to base breakdown voltage	V _{(BR)CBO}	60	—	—	90	—	—	120	—	—	V	I _C = 10 μA, I _E = 0
Collector to emitter breakdown voltage	V _{(BR)CEO}	60	—	—	90	—	—	120	—	—	V	I _C = 1 mA, R _{BE} =
Emitter to base breakdown voltage	V _{(BR)EBO}	5	—	—	5	—	—	5	—	—	V	I _E = 10 μA, I _C = 0
Collector cutoff current	I _{CBO}	—	—	0.1	—	—	0.1	—	—	0.1	μA	V _{CB} = 50 V, I _E = 0
Emitter cutoff current	I _{EBO}	—	—	0.1	—	—	0.1	—	—	0.1	μA	V _{EB} = 2 V, I _C = 0
DC current transfer ratio	h _{FE} ^{*1}	250	—	1200	250	—	1200	250	—	800		V _{CE} = 12 V, I _C = 2 mA
Collector to emitter saturation voltage	V _{CE(sat)}	—	—	0.2	—	—	0.2	—	—	0.2	V	I _C = 10 mA, I _B = 1 mA
Base to emitter voltage	V _{BE}	—	0.6	—	—	0.6	—	—	0.6	—	V	V _{CE} = 12 V, I _C = 2 mA
Gain bandwidth product	f _T	—	90	—	—	90	—	—	90	—	MHz	V _{CE} = 12 V, I _C = 2 mA
Collector output capacitance	Cob	—	3.0	—	—	3.0	—	—	3.0	—	pF	V _{CB} = 10 V, I _E = 0, f = 1 MHz

Note: 1. The 2SC2396, 2SC2543 and 2SC2544 are grouped by h_{FE1} as follows.

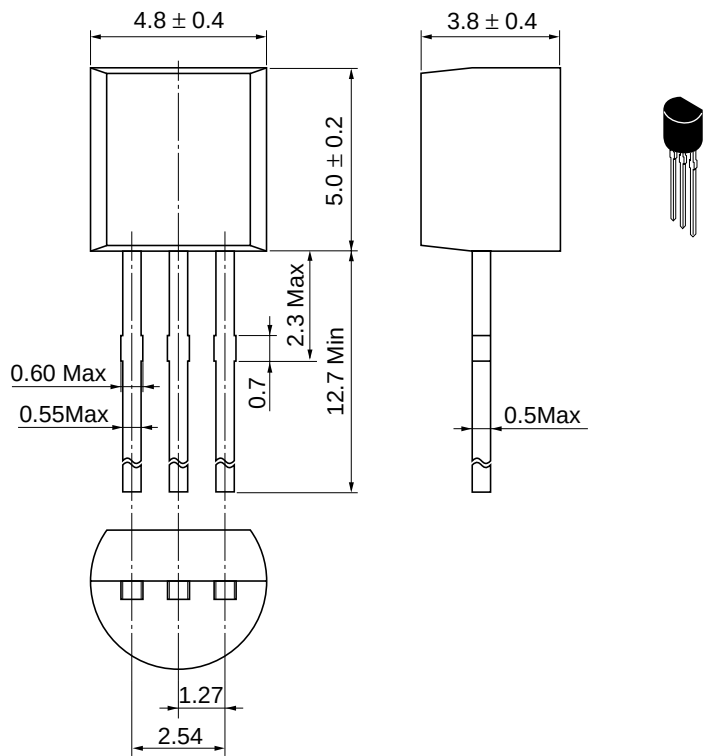
	D	E	F
2SC2396, 2SC2543	250 to 500	400 to 800	600 to 1200
2SC2544	250 to 500	400 to 800	—

See characteristic curves of 2SC2545, 2SC2546 and 2SC2547.



Package Dimensions

As of January, 2001
Unit: mm



Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.25 g

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